



Fundamental Concepts of Charge Transport in Condensed Matter Materials: An Analytical Perspective

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Abstract: This theoretical research article introduces an original conceptual framework the Transport Mode Continuum Theory (TMCT) that restructures the theoretical understanding of charge transport in condensed matter by unifying disparate mechanistic descriptions into a single analytical space. Rather than treating band-like, hopping, and polaron-assisted transport as competing alternatives, the framework positions them as points along continuous axes defined by coherence length, environmental coupling strength, and carrier density. The central theoretical contribution is the derivation of a "Transport Personality Index," a qualitative synthesizer that maps material systems onto archetypal transport regimes based on their positions within this three-dimensional conceptual space. Through logical analysis and conceptual synthesis, the study identifies four fundamental transport personalities Coherent Conductors, Coupled Carriers, Localized Hoppers, and Adaptive Hybrids and demonstrates that transitions between mechanisms represent continuous trajectories rather than discrete switches. The framework further reveals that emergence of unconventional transport phenomena, such as superquadratic carrier-density dependencies and anomalous temperature responses, arises from non-linear cross-domain coupling. This theoretical work is intentionally non-mathematical and non-experimental, focusing purely on analytical model development to provide early-career researchers with an integrative mental model applicable across materials classes, from crystalline semiconductors to disordered molecular solids.

Keywords: charge transport, transport mode continuum, coherence length, environmental coupling, transport personality, condensed matter theory

1. Introduction

1.1 Background and Significance

Charge transport underpins the functionality of virtually all electronic, optoelectronic, and energy-conversion devices. The theoretical description of how electrons and holes navigate through solids, however, remains fractured across multiple conceptual paradigms. Crystalline inorganic semiconductors are conventionally analysed through the lens of band theory, where delocalized Bloch states and scattering events

dominate the narrative. Molecular and amorphous materials, by contrast, are typically discussed in terms of hopping mechanisms, where charge transfer occurs via sequential, thermally activated jumps between localized sites. Polaronic transport introduces yet another vocabulary, emphasizing the self-trapping of carriers through lattice distortion and the resulting activated mobility.

This theoretical pluralism, while historically productive, has generated intellectual silos that impede cross-material learning and predictive design. Researchers studying

organic photovoltaics rarely engage with concepts from oxide electronics, despite shared underlying physics. The fragmentation is exacerbated by the tendency to treat transport mechanisms as mutually exclusive categories band *versus* hopping, coherent *versus* incoherent forcing materials into artificial taxonomies that obscure continuous underlying relationships. Consequently, emerging materials that defy simple classification, such as hybrid perovskites or two-dimensional heterostructures, present theoretical challenges that existing paradigms struggle to accommodate.

1.2 Limitations of Existing Theoretical Approaches

Current theoretical approaches suffer from three analytical constraints. First, they employ mechanistic binarism, forcing a choice between band-like and hopping descriptions even when experimental signatures exhibit blended characteristics. This binary framing arises from the historical development of solid-state physics for perfect crystals and chemistry for molecular systems, leaving mixed-phase materials theoretically orphaned.

Second, existing models rely on parameter isolation, focusing on single descriptors such as mobility edge, reorganization energy, or mean free path without articulating how these parameters co-evolve and couple across material architectures. The band theorist optimizes effective mass while ignoring local electron-phonon coupling; the hopping theorist calculates transfer integrals while neglecting long-range coherence.

Third, conventional frameworks exhibit context rigidity, applying the same conceptual toolkit irrespective of carrier density, excitation density, or environmental conditions. This overlooks how transport personality can shift dramatically when carrier concentration changes from doping-dominated to photoexcitation-dominated regimes, or when dielectric screening alters coupling strength.

1.3 Clear Research Gap

The fundamental theoretical gap is the absence of a unifying analytical scaffold that positions all known transport mechanisms within a continuous, navigable conceptual space. Such a framework must treat mechanism not as a label but as a coordinate, enabling researchers to track how material modifications dimensional confinement, dielectric engineering, defect insertion moves a system through transport space. It must also capture the non-linear coupling between physical descriptors, explaining why certain combinations produce emergent transport anomalies.

1.4 Research Objectives and Contribution

This theoretical research article addresses this gap by developing the Transport Mode Continuum Theory (TMCT), an original analytical framework that accomplishes three objectives:

1. To conceptualize a three-dimensional theoretical space whose axes coherence length, environmental coupling, and carrier density serve as universal coordinates for mapping any condensed matter system's transport behaviour.
2. To derive the "Transport Personality Index," a synthetic construct that qualitatively integrates these three parameters to identify archetypal transport regimes and predict cross-domain coupling effects.
3. To classify materials based on their transport personality rather than chemical composition, revealing that functionally similar transport can arise from chemically disparate systems.

The contribution is purely conceptual: it provides a new mental model that simplifies theoretical navigation while exposing predictive relationships previously obscured by disciplinary boundaries. The framework is intentionally non-mathematical, relying on

logical synthesis and qualitative analysis to maximize accessibility for applied physicists, materials engineers, and chemists.

2. Methodology and Theoretical Approach

2.1 Analytical Methodology: Conceptual Deconstruction and Synthesis

The research methodology follows a conceptual synthesis protocol that deconstructs established transport theories into their foundational physical principles, identifies common analytical parameters across paradigms, and reconstructs these parameters into a unified topological framework.

Stage 1: Theory Deconstruction

Band theory is deconstructed into its reliance on long-range coherence (delocalized wavefunctions) and weak environmental coupling (phonons as perturbative scatterers). Hopping theory is deconstructed into its emphasis on short-range coherence (site-to-site wavefunction overlap) and strong environmental coupling (phonon-assisted transfer). Polaronic theory is deconstructed into its focus on extreme environmental coupling (lattice reorganization) and carrier-induced structural feedback.

Stage 2: Parameter Extraction

From this deconstruction, three parameters emerge as universally relevant across all theories: the characteristic distance over which phase coherence persists (coherence length), the strength of interaction between the carrier and its environment (environmental coupling), and the number density of carriers in the system (carrier density). These parameters are dimensionally independent and physically measurable, yet they have not been previously employed as axes of a unified transport space.

Stage 3: Framework Construction

The three parameters are orthogonalized into a three-dimensional conceptual space. The position of any material system within this

space defines its transport coordinates, which then determine the dominant mechanistic expression and the likelihood of cross-domain emergent phenomena.

2.2 The Transport Mode Continuum Framework

The TMCT framework postulates that all charge transport phenomena can be mapped within a space defined by:

- **Coherence Length (L_c) Axis:** Represents the spatial extent over which an electronic wavefunction maintains a predictable phase relationship. High values correspond to band-like transport; low values correspond to hopping. The axis spans from "Atomic Localization" to "Mesoscopic Delocalization."
- **Environmental Coupling (γ) Axis:** Quantifies the energy exchange rate between the charge carrier and the surrounding lattice or molecular environment. High coupling implies strong polaron formation or phonon-assisted hopping; low coupling implies quasi-elastic scattering. The axis runs from "Weakly Perturbative" to "Strongly Dissipative."
- **Carrier Density (n) Axis:** Captures the average spacing between charge carriers, which influences screening, many-body effects, and percolation pathways. The axis extends from "Dilute, Non-interacting" to "Dense, Correlated."

A material's transport behaviour is not determined by its absolute coordinates but by its relative position and trajectory through this space under varying conditions (temperature, field, illumination).

2.3 Criteria for Theory Integration

The framework integrates only those theoretical elements that satisfy three criteria: (a) parameterizable the element must

influence at least one of the three axes; (b) generality the principle must apply across multiple material classes; and (c) coupling potential the element must interact with at least one other parameter in a way that produces emergent behaviour. Theories focusing on material-specific details (e.g., exact phonon dispersion of a particular crystal) are excluded to preserve generality.

3. Results and Theoretical Analysis

3.1 Derivation of the Transport Personality Index

The central analytical result of this theoretical research is the conceptual derivation of the Transport Personality Index (TPI), defined qualitatively as the vector resultant of a material's coordinates within the TMCT space:

$$\text{TPI} = f(L_c, \gamma, n)$$

While the function f is intentionally left unspecified to avoid mathematical formalism, its conceptual properties are derived analytically:

1. **TPI Isocontours:** Materials lying on the same TPI isocontour (a surface of constant personality) exhibit functionally similar transport despite potentially different chemical compositions. For example, a highly doped polymeric conductor and a lightly doped oxide can share a TPI if their L_c , γ , and n values produce comparable vector magnitudes.
2. **TPI Gradient Effects:** The gradient of TPI across the space predicts the sensitivity of transport to external perturbations. Steep gradients indicate that small changes in coupling or density trigger large mechanistic shifts, explaining phenomena such as the metal-insulator transition.
3. **Cross-Domain Coupling:** The TPI concept reveals that transport anomalies arise not from extreme values on a single axis but from

synchronous movement along multiple axes. For instance, increasing carrier density (n) while simultaneously increasing environmental coupling (γ) can produce super linear mobility enhancements due to screening-induced coupling reduction a feedback loop invisible in single-parameter models.

3.2 Classification of Transport Personalities

By analysing the qualitative behaviour of systems in different octants of the TMCT space, the framework identifies four fundamental transport personalities:

Personality I: Coherent Conductors (High L_c , Low γ , Variable n)

These systems maintain long-range phase coherence and experience minimal environmental disturbance. Transport is quasi-ballistic at low temperatures, with mobility limited primarily by boundary scattering or phonon absorption at elevated temperatures. This personality includes crystalline semiconductors (Si, GaAs) and high-mobility two-dimensional electron gases. The TPI predicts that in this regime, mobility decreases weakly with temperature (T^{-1}) and is relatively insensitive to carrier density until degenerate doping levels are reached.

Personality II: Coupled Carriers (Moderate L_c , High γ , Low n)

Characterized by strong carrier-environment interaction but low carrier density, this personality describes small-polaron formation in oxides and molecular crystals. The carrier becomes dressed by a local distortion cloud, and transport proceeds via thermally activated hopping. The TPI analysis reveals that mobility exhibits Arrhenius temperature dependence and is highly sensitive to dielectric screening, which can modulate γ and shift the system toward Personality III.

Personality III: Localized Hoppers (Low L_c , Moderate γ , High n)

In this octant, carriers are spatially localized (short coherence) but exist at high density, enabling percolation pathways through overlapping Coulomb potentials. Disordered organic semiconductors and heavily defected oxides often exhibit this personality. The TPI predicts that transport is dominated by variable-range hopping, with mobility showing a complex temperature dependence (Mott's law) and a threshold carrier density for percolation conduction.

Personality IV: Adaptive Hybrids (Moderate L_c , Variable γ , Variable n)

This personality occupies a central region of the TMCT space where all parameters are moderate and dynamically tunable. Hybrid perovskites, van der Waals heterostructures, and doped polymer blends fall here. The TPI framework predicts that these materials display **mechanistic plasticity**, transitioning between band-like and hopping behaviour in response to modest stimuli (illumination, gate voltage). This plasticity emerges from cross-domain coupling: increased carrier density (n) screens environmental coupling (γ), which in turn extends coherence length (L_c), creating a positive feedback loop that can abruptly shift the system toward Personality I.

3.3 Theoretical Derivation of Cross-Domain Coupling Effects

A key analytical result is the identification of coupling operators that describe how movement along one TMCT axis influences the effective position on another:

- **Operator $\Omega(L_c \rightarrow \gamma)$:** As coherence length shortens (L_c decreases), the carrier's wavefunction becomes more localized, intensifying its interaction with local phonon modes and increasing effective environmental coupling (γ). This operator explains why nanostructuring a bulk crystal can induce polaron-like behavior even in weakly polar materials.

- **Operator $\Psi(n \rightarrow L_c)$:** Increasing carrier density (n) enhances screening of disorder potentials, which can extend coherence length (L_c) by reducing scattering. However, at very high densities, carrier-carrier scattering can localize states, causing L_c to decrease again. The TPI captures this non-monotonic relationship as a fold in transport personality space.
- **Operator $\Theta(\gamma \rightarrow n_{eff})$:** Strong environmental coupling (γ) can generate local electric fields through lattice polarization, effectively increasing the local carrier concentration (n_{eff}) through field-induced ionization of trap states. This feedback mechanism is particularly relevant in ferroelectric materials where polarization domains act as local doping agents.

These operators are derived through logical analysis of physical interactions, not from mathematical derivations, yet they provide predictive power. For example, applying Ω predicts that reducing the dimensionality of a material (shortening L_c) will inevitably increase its susceptibility to phonon coupling, guiding design trade-offs in nanoelectronics.

3.4 Emergent Transport Phenomena as TMCT Trajectories

The framework analytically predicts several emergent phenomena that appear anomalous within single-mechanism models:

Superquadratic Density Dependence: In materials near the Personality III-IV boundary, increasing carrier density can trigger a percolation avalanche that extends coherence length through screening, leading to mobility increases proportional to n^2 or higher. The TPI interprets this not as a new physical law but as a trajectory crossing a cusp in the transport space.

Inverted Temperature Response: Some hybrid materials show mobility increasing with temperature in specific ranges. Within TMCT, this corresponds to a system trapped at low temperature in a high- γ , low- L_c configuration (Personality II). Thermal activation reduces coupling (γ) by accessing higher-symmetry lattice configurations, moving the system toward Personality IV and increasing mobility an effect analogous to entropy-driven delocalization.

Field-Induced Mechanism Switching: Applied electric fields can dynamically alter transport personality by Stark-shifting local potentials, effectively moving a material along the L_c axis. The framework predicts that the critical field strength for mechanism switching scales inversely with initial coherence length, offering a design rule for field-effect transistors.

4. Discussion

4.1 Interpretation of TMCT and TPI

The Transport Mode Continuum Theory represents a paradigmatic shift from mechanism-based classification to coordinate-based analysis. By treating transport as a continuous property of a conceptual space, the framework dissolves artificial boundaries between solid-state physics and chemical theories, enabling a unified language for materials as diverse as perovskite solar cells and oxide catalysts.

The TPI concept functions as a qualitative compass rather than a quantitative metric. Its value lies in enabling researchers to estimate how processing conditions, doping strategies, or dimensional constraints will reposition a material within transport space. For instance, introducing strain in a semiconductor extends L_c by reducing scattering, but may also increase γ by enhancing electron-phonon coupling. The TPI predicts whether the net effect will improve or degrade overall transport based on the relative magnitudes of these shifts.

4.2 Comparison with Existing Theoretical Perspectives

Conventional band theory focuses exclusively on the high- L_c , low- γ quadrant of TMCT, providing an incomplete map of the full transport space. Hopping theory, conversely, maps only the low- L_c , moderate- γ region. Polaron theory enriches the high- γ axis but typically assumes low n and static L_c .

Recent computational approaches, such as combining density functional theory with kinetic Monte Carlo, effectively sample points across the TMCT space but lack an overarching conceptual scaffold to interpret the results. The TMCT provides this scaffold, allowing computational data points to be connected into trajectories that reveal underlying design principles.

Machine learning studies that predict mobility from structural descriptors can be reinterpreted through TMCT as learning the implicit mapping between atomic configurations and transport coordinates. The framework suggests that training on L_c , γ , and n -derived features would improve model interpretability and transferability across material classes.

4.3 Practical and Interdisciplinary Implications

For **applied physicists** designing low-dimensional devices, the Ω operator offers a crucial insight: reducing device dimensions to improve electrostatic control inevitably strengthens environmental coupling, potentially degrading mobility. Optimal device design must therefore engineer dielectric environments (e.g., hexagonal boron nitride encapsulation) to offset this effect, preserving high L_c while achieving confinement.

For **materials engineers** developing hybrid perovskites, the Adaptive Hybrid personality explains why these materials exhibit both high mobility and slow recombination: under photoexcitation (high n), the system shifts

toward Personality I (extended coherence), while in dark regions (low n), it reverts to Personality II (localized, trapped states). This spatiotemporal heterogeneity is a feature, not a flaw, that can be optimized by controlling carrier injection profiles.

For **chemists** synthesizing molecular semiconductors, the TPI suggests that increasing conjugation length (extending L_c) will only improve mobility if environmental coupling (γ) is simultaneously suppressed through side-chain engineering that reduces reorganization energy. The framework thus guides synthetic strategies toward coherent design rather than single-parameter optimization.

4.4 Limitations of the Theoretical Framework

The TMCT is intentionally qualitative and topological; it provides directional guidance but cannot predict numerical values for mobility or conductivity without parameterization. The axes are conceptual constructs that correlate with but do not directly equal specific physical quantities (e.g., coherence length is not precisely the phase-breaking length, but captures its essence).

The framework also assumes parameter orthogonality, which may break down under extreme conditions where L_c , γ , and n become coupled through non-linear feedback that collapses the dimensionality of the space. Additionally, it currently neglects explicit time dependence, treating transport as a quasi-static property of a material's "personality" rather than a dynamic evolution.

Finally, the classification into four personalities is a conceptual simplification; real materials likely exhibit hybrid personalities or occupy transitional regions. The framework's value lies in providing a starting vocabulary for more nuanced analysis rather than a rigid taxonomy.

5. Limitations of the Study

This theoretical research is deliberately confined to conceptual model development. The study does not calibrate the TMCT axes against experimental data or provide algorithms for calculating TPI values. The analytical methodology, while logically rigorous, remains qualitative and awaits quantitative validation through computational mapping.

Key assumptions underlying the framework include: (i) that coherence length, environmental coupling, and carrier density are conceptually separable parameters; (ii) that transport mechanisms transition smoothly rather than abruptly across the space; and (iii) that cross-domain coupling operators are monotonic and predictable. These assumptions, while reasonable for a wide material range, may fail in strongly correlated systems where parameters entangle quantum mechanically.

The framework also omits explicit treatment of extrinsic factors such as contact resistance, grain boundaries, and interfacial dipoles, focusing instead on intrinsic bulk properties. Extending TMCT to include interfacial dimensions would increase its applicability to real devices but lies beyond the present scope.

6. Future Research Directions

6.1 Computational Parameterization of TMCT

The immediate theoretical extension involves computational mapping of known materials onto the TMCT space. Density functional theory can estimate coherence length from wavefunction delocalization, electron-phonon coupling calculations can quantify γ , and doping or excitation levels provide n . Clustering these calculated coordinates would validate the four archetypal personalities and reveal the functional forms of the cross-domain coupling operators.

6.2 Integration with Machine Learning

The TMCT axes offer a physically interpretable feature set for machine learning

models predicting transport properties. Rather than using raw atomic coordinates, training on L_c , γ , and n could improve generalization across material classes and enable inverse design: specifying a desired TPI and having the model propose material compositions and structures to realize it.

6.3 Dynamic TMCT Extensions

Future theoretical work should incorporate time as a fourth dimension, creating a dynamic TMCT that tracks how transport personality evolves under operational stimuli (electric fields, optical excitation, temperature ramps). This would capture phenomena such as bias stress instability and light-soaking effects, which represent temporal trajectories through transport space.

6.4 Device-Scale TMCT

Extending the framework from bulk materials to device architectures requires introducing interfacial coupling axes that capture how contacts and dielectrics renormalize the effective L_c , γ , and n of the active layer. This multi-scale TMCT would bridge atomic-scale physics to circuit-level performance, directly addressing the needs of applied engineering.

7. Conclusion

This theoretical research article has developed the Transport Mode Continuum Theory (TMCT), an original conceptual framework that unifies the theoretical description of charge transport in condensed matter materials. By introducing three analytical axes coherence length, environmental coupling, and carrier density and deriving the Transport Personality Index as a synthesizing construct, the framework dissolves artificial boundaries between band, hopping, and polaron-based models. The classification of materials into four transport personalities provides a new typology based on functional behaviour rather than chemical identity, while the derived coupling operators predict how modifications along one axis inevitably influence others.

The TMCT's central contribution is conceptual: it provides a navigational map for applied physicists, materials engineers, and chemists to reason about transport design, predict emergent phenomena, and communicate across disciplinary divides. By emphasizing analytical synthesis over mathematical formalism and logical derivation over empirical fitting, the framework maintains accessibility while advancing theoretical frontiers. Future work parameterizing and extending TMCT promises to transform it from a qualitative compass into a predictive tool, accelerating the development of next-generation electronic and energy materials.

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